RF Low Noise FET<br>CE3514M4

## 12GHz Low Noise FET in Dual Mold Plastic PKG

## DESCRIPTION

- Low Noise and High Gain
- Original Dual Mold Plastic package


## FEATURES

- Low noise figure and high associated gain $\mathrm{NF}=0.42 \mathrm{~dB}$ TYP., $\mathrm{Ga}=12.2 \mathrm{~dB}$ TYP. @VDS=2V, $\mathrm{ID}=10 \mathrm{~mA}, \mathrm{f}=12 \mathrm{GHz}$


## PACKAGE

- Flat-lead 4-pin thin-type super minimold package


## APPLICATIONS

- DBS LNB gain-stage, Mix-stage
- Low noise amplifier for microwave communication systems


## ORDERING INFORMATION

| Part Number | Order Number | Package | Marking | Description |
| :--- | :--- | :--- | :---: | :---: |
| CE3514M4 | CE3514M4-C2 | Flat-lead 4-pin <br> thin-type super <br> minimold <br> package | C0F | • Embossed tape 8 mm wide <br> $\cdot$ Pin 1 (Source), Pin 2 (Drain) <br> Face the perforation side of <br> the Tape <br> - MOQ 15 kpcs/reel |
|  |  |  |  |  |

## PIN CONFIGURATION :



| PIN No. | PIN Name |
| :---: | :---: |
| 1 | Source |
| 2 | Drain |
| 3 | Source |
| 4 | Gate |
|  |  |

## ABSOLUTE MAXIMUM RATINGS

(TA $=+25^{\circ} \mathrm{C}$, unless otherwise specified)

| Parameter | Symbol | Rating | Unit |
| :--- | :---: | :---: | :---: |
| Drain to Source Voltage | $\mathrm{V}_{\mathrm{DS}}$ | 4.0 | V |
| Gate to Source Voltage | $\mathrm{V}_{\mathrm{GS}}$ | -3.0 | V |
| Drain Current | $\mathrm{I}_{\mathrm{D}}$ | $\mathrm{I}_{\mathrm{DSS}}$ | mA |
| Gate Current | $\mathrm{I}_{\mathrm{G}}$ | 80 | $\mu \mathrm{~A}$ |
| Total Power Dissipation | $\mathrm{P}_{\mathrm{tot}}$ | 125 | mW |
| Channel Temperature | $\mathrm{T}_{\mathrm{ch}}$ | +150 | ${ }^{\circ} \mathrm{C}$ |
| Storage Temperature | $\mathrm{T}_{\text {stg }}$ | -55 to +125 | ${ }^{\circ} \mathrm{C}$ |
| Operation Temperature | $\mathrm{T}_{\text {op }}$ | -55 to $+125^{\text {Note }}$ | ${ }^{\circ} \mathrm{C}$ |

Note Refer to Total Power Dissipation vs. Ambient Temperature graph on page 4

## RECOMMENDED OPERATING RANGE

(TA $=+25^{\circ} \mathrm{C}$, unless otherwise specified)

| Parameter | Symbol | MIN. | TYP. | MAX. | Unit |
| :--- | :---: | :---: | :---: | :---: | :---: |
| Drain to Source Voltage | $\mathrm{V}_{\mathrm{DS}}$ | +1 | +2 | +3 | V |
| Drain Current | $\mathrm{I}_{\mathrm{D}}$ | 5 | 10 | 15 | mA |

## ELECTRICAL CHARACTERISTICS

(TA $=+25^{\circ} \mathrm{C}$, unless otherwise specified)

| Parameter | Symbol | Condition | MIN. | TYP. | MAX. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Gate to Source Leak Current | IGso | $\mathrm{V}_{\mathrm{GS}}=-3.0 \mathrm{~V}$ | - | 0.4 | 10 | $\mu \mathrm{A}$ |
| Saturated Drain Current | IDss | $\mathrm{V}_{\mathrm{DS}}=2 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=0 \mathrm{~V}$ | 27 | 47.5 | 68 | mA |
| Gate to Source Cut-off Voltage | $\mathrm{V}_{\mathrm{GS} \text { (off) }}$ | $\mathrm{V}_{\mathrm{DS}}=2 \mathrm{~V}, \mathrm{I}_{\mathrm{D}}=120 \mu \mathrm{~A}$ | -1.10 | -0.75 | -0.39 | V |
| Transconductance | Gm | $V_{D S}=2 \mathrm{~V}, \mathrm{I}_{\mathrm{D}}=10 \mathrm{~mA}$ | 54 | 69 | - | mS |
| Noise Figure | NF | $\begin{gathered} V_{D S}=2 V, I_{D}=10 \mathrm{~mA}, \\ f=12 G H z \end{gathered}$ | - | 0.42 | 0.62 | dB |
| Associated Gain | Ga |  | 10.5 | 12.2 | - | dB |

CE3514M4

## TYPICAL CHARACTERISTICS :

(TA $=+25^{\circ} \mathrm{C}$, unless otherwise specified)


DRAIN CURRENT VS.
GATE TO SOURCE VOLTAGE


DRAIN CURRENT VS. DRAIN TO SOURCE VOLTAGE


MINIMUM NOISE FIGURE \& ASSOCIATED GAIN VS. DRAIN CURRENT


## S-PARAMETERS

S-Parameters are available on the CEL web site.

## RECOMMENDED SOLDERING CONDITIONS

Recommended Soldering Conditions are provided on the CEL web site.

## PACKAGE DIMENSIONS



## REVISION HISTORY

| Version | Change to current version | Page(s) |
| :--- | :--- | :---: |
| CDS-0021-02 (Issue A) | Initial datasheet | $\mathrm{N} / \mathrm{A}$ |

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